



Attorney's Docket No.: 07977/208001/US3511

#17/Pre-L  
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Shunpei Yamazaki, et al. Art Unit : 2823  
Serial No.: 08/994,038 Examiner : W. David Coleman  
Filed : December 18, 1997  
Title : CHARGE TRANSFER SEMICONDUCTOR DEVICE AND MANUFACTURING  
METHOD THEREOF

Commissioner for Patents  
Washington, D.C. 20231

PRELIMINARY AMENDMENT

RECEIVED

OCT 10 2000

TECHNOLOGY CENTER 2800

Sir:

Prior to initial examination, kindly amend the above-identified application as follows:

In the Claims:

Please amend the following claims.

Please amend claims 1 as follows.

1. (Amended) A charge transfer semiconductor device comprising:
- a crystalline semiconductor film having a plurality of crystals extending in a crystal growth direction;

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

September 28, 2000

Date of Deposit

Signature

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